

# Contents

## 1. Introduction

1.1	A Survey of Semiconductors	2
1.1.1	Elemental Semiconductors	2
1.1.2	Binary Compounds	2
1.1.3	Oxides	3
1.1.4	Layered Semiconductors	3
1.1.5	Organic Semiconductors	4
1.1.6	Magnetic Semiconductors	4
1.1.7	Other Miscellaneous Semiconductors	4
1.2	Growth Techniques	5
1.2.1	Czochralski Method	5
1.2.2	Bridgman Method	6
1.2.3	Chemical Vapor Deposition	6
1.2.4	Molecular Beam Epitaxy	7
1.2.5	Liquid Phase Epitaxy	10
	Summary	11

## 2. Electronic Band Structures

2.1	Quantum Mechanics	14
2.2	Translational Symmetry and Brillouin Zones	16
2.3	A Pedestrian's Guide to Group Theory	21
2.3.1	Definitions and Notations	21
2.3.2	Symmetry Operations of the Diamond and Zinc-Blende Structures	26
2.3.3	Representations and Character Tables	28
2.3.4	Some Applications of Character Tables	35
2.4	Empty Lattice or Nearly Free Electron Energy Bands	43
2.4.1	Nearly Free Electron Band Structure in a Zinc-Blende Crystal	44
2.4.2	Nearly Free Electron Energy Band in Diamond Crystals	48
2.5	Band Structure Calculation by Pseudopotential Methods	54
2.5.1	Pseudopotential Form Factors in Zinc-Blende- and Diamond-Type Semiconductors	57
2.5.2	Empirical and Self-Consistent Pseudopotential Methods	61
2.6	The $k\cdot p$ Method of Band-Structure Calculations	63
2.6.1	Effective Mass of a Nondegenerate Band Using the $k\cdot p$ Method	64

2.6.2	Band Dispersion near a Degenerate Extremum: Top Valence Bands in Diamond- and Zinc-Blende-Type Semiconductor	67
2.7	Tight-Binding or LCAO Approach to the Band Structure of Semiconductor	78
2.7.1	Molecular Orbitals and Overlap Parameters	78
2.7.2	Band Structure of Group-IV Elements by the Tight-Binding Method	82
2.7.3	Overlap Parameters and Nearest-Neighbor Distances	89
	Problems	91
	Summary	98
<b>3.</b>	<b>Vibrational Properties of Semiconductors, and Electron-Phonon Interactions</b>	
3.1	Phonon Dispersion Curves of Semiconductors	102
3.2	Models for Calculating Phonon Dispersion Curves of Semiconductors	105
3.2.1	Force Constant Models	105
3.2.2	Shell Model	106
3.2.3	Bond Models	107
3.2.4	Bond Charge Models	109
3.3	Electron-Phonon Interactions	113
3.3.1	Strain Tensor and Deformation Potentials	114
3.3.2	Electron-Acoustic-Phonon Interaction at Degenerate Bands	119
3.3.3	Piezoelectric Electron-Acoustic-Phonon Interaction	122
3.3.4	Electron-Optical-Phonon Deformation Potential Interactions	123
3.3.5	Fröhlich Interaction	125
3.3.6	Interaction Between Electrons and Large-Wavevector Phonons: Intervalley Electron-Phonon Interaction	127
	Problems	129
	Summary	147
<b>4.</b>	<b>Electronic Properties of Defects</b>	
4.1	Classification of Defects	150
4.2	Shallow or Hydrogenic Impurities	151
4.2.1	Effective Mass Approximation	152
4.2.2	Hydrogenic or Shallow Donors	156
4.2.3	Donors Associated with Anisotropic Conduction Bands	161
4.2.4	Acceptor Levels in Diamond- and Zinc-Blende-Type Semiconductors	164
4.3	Deep Centers	170
4.3.1	Green's Function Method for Calculating Defect Energy Levels	173

4.3.2	An Application of the Green's Function Method: Linear Combination of Atomic Orbitals	177
4.3.3	An Application of the Green's Function Method: Nitrogen in GaP and GaAsP Alloys	182
4.3.4	Final Note on Deep Centers	187
	Problems	187
	Summary	192

## 5. Electrical Transport

5.1	Quasi-Classical Approach	193
5.2	Carrier Mobility for a Nondegenerate Electron Gas	196
5.2.1	Relaxation Time Approximation	196
5.2.2	Nondegenerate Electron Gas in a Parabolic Band	197
5.2.3	Dependence of Scattering and Relaxation Times on Electron Energy	198
5.2.4	Momentum Relaxation Times	199
5.2.5	Temperature Dependence of Mobilities	210
5.3	Modulation Doping	213
5.4	High-Field Transport and Hot Carrier Effects	215
5.4.1	Velocity Saturation	217
5.4.2	Negative Differential Resistance	218
5.4.3	Gunn Effect	220
5.5	Magneto-Transport and the Hall Effect	222
5.5.1	Magneto-Conductivity Tensor	222
5.5.2	Hall Effect	224
5.5.3	Hall Coefficient for Thin Film Samples (van der Pauw Method)	225
5.5.4	Hall Effect for a Distribution of Electron Energies	226
	Problems	227
	Summary	231

## 6. Optical Properties I

6.1	Macroscopic Electrodynamics	234
6.1.1	Digression: Units for the Frequency of Electromagnetic Waves	237
6.1.2	Experimental Determination of Optical Constants	237
6.1.3	Kramers-Kronig Relations	240
6.2	The Dielectric Function	243
6.2.1	Experimental Results	243
6.2.2	Microscopic Theory of the Dielectric Function	244
6.2.3	Joint-Density of States and Van Hove Singularities	251
6.2.4	Van Hove Singularities in $\epsilon_i$	252
6.2.5	Direct Absorption Edges	258
6.2.6	Indirect Absorption Edges	259
6.2.7	"Forbidden" Direct Absorption Edges	263

6.3	Excitons	266
6.3.1	Exciton Effect at $M_0$ Critical Points	269
6.3.2	Absorption Spectra of Excitons	272
6.3.3	Exciton Effect at $M_1$ Critical Points or Hyperbolic Excitons	278
6.3.4	Exciton Effect at $M_3$ Critical Points	281
6.4	Phonon-Polaritons and Lattice Absorption	282
6.4.1	Phonon-Polaritons	285
6.4.2	Lattice Absorption and Reflection	288
6.4.3	Multiphonon Lattice Absorption	289
6.4.4	Dynamic Effective Ionic Charges in Heteropolar Semiconductors	293
6.5	Absorption Associated with Extrinsic Electrons	295
6.5.1	Free Carrier Absorption in Doped Semiconductors	296
6.5.2	Absorption by Carriers Bound to Shallow Donors and Acceptors	301
6.6	Modulation Spectroscopy	305
6.6.1	Frequency Modulated Reflectance and Thermoreflectance	309
6.6.2	Piezoreflectance	311
6.6.3	Electroreflectance (Franz-Keldysh Effect)	312
6.6.4	Photoreflectance	319
6.6.5	Reflectance Difference Spectroscopy	322
	Problems	323
	Summary	331

## 7. Optical Properties II

7.1	Emission Spectroscopies	333
7.1.1	Band-to-Band Transitions	339
7.1.2	Free-to-Bound Transitions	342
7.1.3	Donor-Acceptor Pair Transitions	344
7.1.4	Excitons and Bound Excitons	350
7.1.5	Luminescence Excitation Spectroscopy	357
7.2	Light Scattering Spectroscopies	362
7.2.1	Macroscopic Theory of Inelastic Light Scattering by Phonons	362
7.2.2	Raman Tensor and Selection Rules	365
7.2.3	Experimental Determination of Raman Spectra	371
7.2.4	Microscopic Theory of Raman Scattering	379
7.2.5	A Detour into the World of Feynman Diagrams	381
7.2.6	Brillouin Scattering	385
7.2.7	Experimental Determination of Brillouin Spectra	387
7.2.8	Resonant Raman and Brillouin Scattering	388
	Problems	409
	Summary	413

## 8. Photoelectron Spectroscopy

8.1	Photoemission	419
8.1.1	Angle-Integrated Photoelectron Spectra of the Valence Bands	428
8.1.2	Angle-Resolved Photoelectron Spectra of the Valence Bands	431
8.1.3	Core Levels	439
8.2	Inverse Photoemission	444
8.3	Surface Effects	445
8.3.1	Surface States and Surface Reconstruction	445
8.3.2	Surface Energy Bands	446
8.3.3	Fermi Level Pinning and Space Charge Layers	448
	Problems	453
	Summary	455

## 9. Effect of Quantum Confinement on Electrons and Phonons in Semiconductors

9.1	Quantum Confinement and Density of States	458
9.2	Quantum Confinement of Electrons and Holes	461
9.2.1	Semiconductor Materials for Quantum Wells and Superlattices	462
9.2.2	Classification of Multiple Quantum Wells and Superlattices	464
9.2.3	Confinement Energy Levels of Electrons and Holes	465
9.2.4	Some Experimental Results	475
9.3	Phonons in Superlattices	480
9.3.1	Phonons in Superlattices: Folded Acoustic and Confined Optic Modes	480
9.3.2	Folded Acoustic Modes: Macroscopic Treatment	485
9.3.3	Confined Optical Modes: Macroscopic Treatment	486
9.3.4	Electrostatic Effects in Polar Crystals: Interface Modes	488
9.4	Raman Spectra of Phonons in Semiconductor Superlattices	497
9.4.1	Raman Scattering by Confined Acoustic Phonons	497
9.4.2	Raman Scattering by Confined Optical Phonons	502
9.4.3	Raman Scattering by Interface Modes	504
9.4.4	Macroscopic Models of Electron-LO Phonon (Fröhlich) Interaction in Multiple Quantum Wells	507
9.5	Electrical Transport: Resonant Tunneling	511
9.5.1	Resonant Tunneling Through a Double-Barrier Quantum Well	512
9.5.2	I-V Characteristics of Resonant Tunneling Devices	515
9.6	Quantum Hall Effects in Two-Dimensional Electron Gases	519
9.6.1	Landau Theory of Diamagnetism in a Three-Dimensional Free Electron Gas	520

9.6.2	Magneto-Conductivity of a Two-Dimensional Electron Gas: Filling Factor . . . .	523
9.6.3	The Experiment of von Klitzing, Pepper and Dorda . . .	524
9.6.4	Explanation of the Hall Plateaus in the Integral Quantum Hall Effect . . . . .	527
9.7	Concluding Remarks . . . . .	531
	Problems . . . . .	532
	Summary . . . . .	535

### Appendix: Pioneers of Semiconductor Physics Remember... ████████████████████

	Ultra-Pure Germanium: From Applied to Basic Research or an Old Semiconductor Offering New Opportunities By <i>Eugene E. Haller</i> . . . . .	539
	Two Pseudopotential Methods: Empirical and Ab Initio By <i>Marvin L. Cohen</i> . . . . .	542
	The Early Stages of Band-Structures Physics and Its Struggles for a Place in the Sun By <i>Conyers Herring</i> . . . . .	544
	Cyclotron Resonance and Structure of Conduction and Valence Band Edges in Silicon and Germanium By <i>Charles Kittel</i> . . . . .	547
	Optical Properties of Amorphous Semiconductors and Solar Cells By <i>Jan Tauc</i> . . . . .	550
	Optical Spectroscopy of Shallow Impurity Centers By <i>Elias Burstein</i> . . . . .	553
	On the Prehistory of Angular Resolved Photoemission By <i>Neville V. Smith</i> . . . . .	558
	The Discovery and Very Basics of the Quantum Hall Effect By <i>Klaus von Klitzing</i> . . . . .	560
	The Birth of the Semiconductor Superlattice By <i>Leo Esaki</i> . . . . .	562

**References** ████████████████████ 567

**Subject Index** ████████████████████ 599